

Flangeless Termination 250 Watts, 50Ω

Description:

The E250N50X4 is high performance Aluminum Nitride (AIN) termination intended as a cost competitive alternative to Beryllium Oxide (BeO). The termination is well suited to all cellular frequency bands such as; AMPS, GSM, DCS, PCS, PHS and UMTS. The high power handling makes the part ideal for terminating circulators and for use in power combiners. The termination is also RoHS compliant!

General Specifications:

Resistive Element	Thick film
Substrate	AIN Ceramic
Terminal Finish	Matte Tin over Nickel Barrier
Operating Temperature	-50 to +200°C(see de rating chart)

Electrical Specifications:

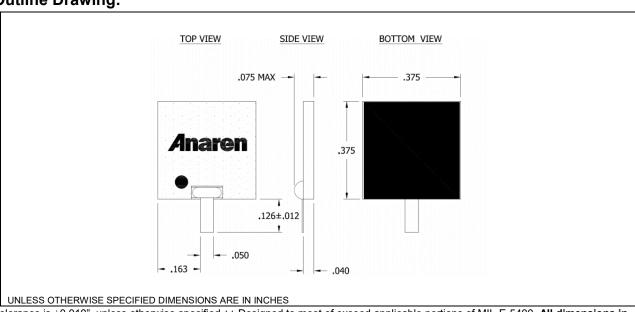
Resistance Value:	50 Ohms, ±2%
Power:	250 Watts
Frequency Range:	DC – 2.2 GHz
Return Loss	>20 dB DC – 2.2 GHz

Specification based on unit properly installed using suggested mounting instructions and a 50 ohm nominal impedance. Specifications subject to change.

Features:

- RoHS Compliant
- 250 Watts
- DC 2.2GHz
- AIN Ceramic
- Non-Nichrome Resistive Element
- Low VSWR
- 100% Tested

Outline Drawing:



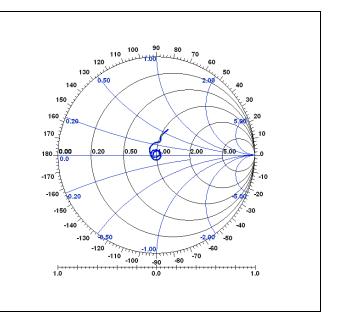
Tolerance is ± 0.010 ", unless otherwise specified. $\pm \pm$ Designed to meet of exceed applicable portions of MIL-E-5400. **All dimensions in inches.**



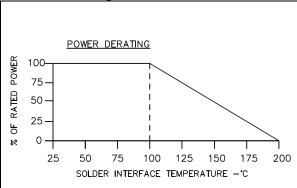


Typical Performance:



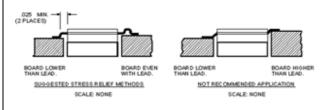


Power de-rating:



*Actual performance could be limited by the solder properties of the application

Mounting Footprint:



SUGGESTED MOUNTING PROCEDURE

- MAKE SURE THAT THE DEVICES ARE MOUNTED ON FLAT SURFACES (.001" UNDER THE DEVICE) TO OPTIMIZE THE HEAT TRANSFER.
- POSITION DEVICE ON MOUNTING SURFACE AND SOLDER IN PLACE USING AN APPROPRIATE SOLDER.
- SOLDER LEADS IN PLACE USING AN APPROPRIATE SOLDER TYPE WITH A CONTROLLED TEMPERATURE IRON.

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